TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

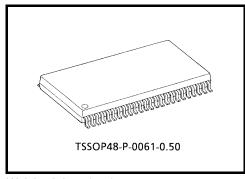
TC74LCX16245AFT

Low-Voltage 16-Bit Bus Transceiver with 5-V Tolerant Inputs and Outputs

The TC74LCX16245AFT is a high-performance CMOS 16-bit bus transceiver. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 16-bit bus transceiver is controlled by direction control (DIR) inputs and output enable (\overline{OE}) inputs which are common to each byte. It can be used as two 8-bit transceiver or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The \overline{OE} inputs can be used to disable the device so that the busses are effectively isolated.



Weight: 0.25 g (typ.)

All inputs are equipped with protection circuits against static discharge.

Features (Note)

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pd} = 5.2 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Package: TSSOP (thin shrink small outline package)
- Bidirectional interface between 5.0 V and 3.3 V signals
- · Power-down protection provided on all inputs and outputs

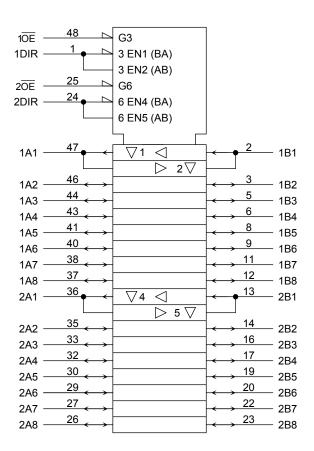
Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input level fixed by means of pull-up or pull-down resistors.

Pin Assignment (top view)

1DIR 48 10E 1B1 2 47 1A1 3 1B2 1A2 46 GND 4 **GND** 45 5 1B3 1A3 1B4 6 43 1A4 V_{CC} 7 42 V_{CC} 1B5 8 41 1A5 1B6 9 1A6 40 GND 10 **GND** 39 1B7 11 38 1A7 1B8 12 37 1A8 2B1 13 36 2A1 2B2 14 35 2A2 GND 15 GND 34 2B3 16 33 2A3 2B4 17 32 2A4 V_{CC} 18 31 V_{CC} 2B5 19 2A5 30 2B6 20 29 2A6 GND 21 28 **GND** 2B7 22 27 2A7 2B8 23 26 2A8 2DIR 24 2OE 25

IEC Logic Symbol



Truth Table

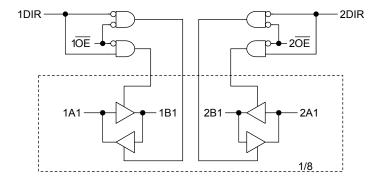
Inputs		Function		
1OE	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	Outputs
L	L	Output	Input	A = B
L	Н	Input Output		B=A
Н	Х	Z		Z

Inputs		Function			
2 OE	2DIR	Bus Bus 2A1-2A8 2B1-2B8		Outputs	
L	L	Output	Input	A = B	
L	Н	Input Output		B = A	
Н	Х	Z		Z	

X: Don't care

Z: High impedance

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	−0.5 to 7.0	V
DC input voltage (DIR, $\overline{\text{OE}}$)	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC bus I/O voltage	V _{I/O}	-0.5 to V _{CC} + 0.5	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	P_{D}	400	mW
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.0 to 3.6	V	
1 ower supply voltage	vcc	1.5 to 3.6 (Note 2)	V	
Input voltage (DIR, $\overline{\text{OE}}$)	V _{IN}	0 to 5.5	٧	
Bus I/O voltage	V	0 to 5.5 (Note 3)	V	
bus I/O voltage	V _{I/O}	0 to V _{CC} (Note 4)		
Output current	1/1	±24 (Note 5)	mA	
Output current	I _{OH} /I _{OL}	±12 (Note 6)	ША	
Operating temperature	T _{opr}	–40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
		Cymbol	1001 00					
Input voltage	H-level	V _{IH}	_	_	2.7 to 3.6	2.0	_	V
input voltage	L-level	V _{IL}	_	_	2.7 to 3.6	_	0.8	V
				$I_{OH} = -100 \mu A$	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	V
			$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \ \mu A$	2.7 to 3.6	_	0.2	
	L-level	Vai		$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	L-level	V _{OL}		$I_{OL} = 16 \text{ mA}$	3.0	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μА
3-state output OFF st	ate current	I _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μА
Power-off leakage cu	rrent	loff	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μΑ
Quiescent supply current		<u> </u>	V _{IN} = V _{CC} or GND		2.7 to 3.6	_	20.0	
		ICC	I_{CC} $V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±20.0	μΑ
Increase in Icc per inp	c per input ΔI_{CC} $V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	500			



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	6.2	ns
Tropagation delay time	t _{pHL}	i igure 1, i igure 2	3.3 ± 0.3	1.5	5.2	
2 state submit smaller times	t _{pZL}	Figure 1, Figure 3	2.7		7.5	ns
3-state output enable time	t _{pZH}		3.3 ± 0.3	1.5	6.5	
3-state output disable time	t _{pLZ}	2.7		7.0	ns	
3-state output disable time	t_{pHZ}	Figure 1, Figure 3	3.3 ± 0.3	1.5	6.0	115
Output to output allow	t _{osLH}	(Alata)	2.7			ns
Output to output skew	t _{osHL}	(Note)	3.3 ± 0.3		1.0	115

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	٧
Quiet output minimum dynamic V _{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	٧

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Bus input capacitance	C _{I/O}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note	3.3	25	pF

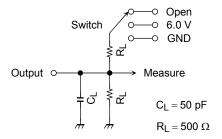
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

6

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

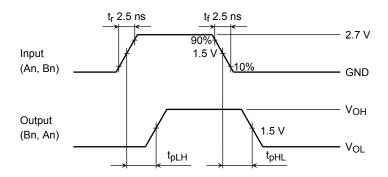


Figure 2 t_{pLH}, t_{pHL}

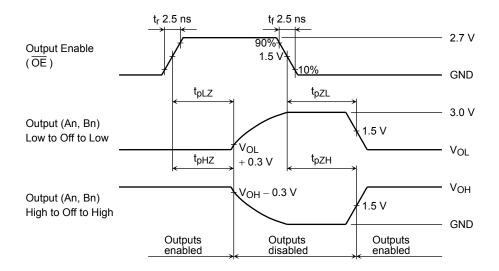
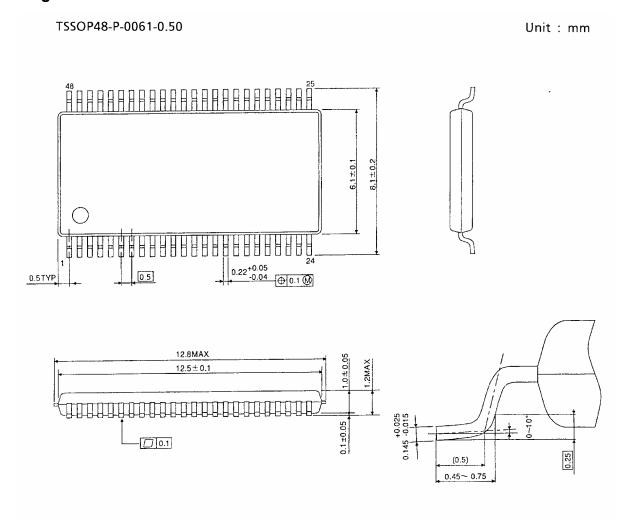


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Package Dimensions

TOSHIBA



8

Weight: 0.25 g (typ.)

Note: Lead (Pb)-Free Packages

TSSOP48-P-0061-0.50

RESTRICTIONS ON PRODUCT USE

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
 may result from its use. No license is granted by implication or otherwise under any patents or other rights of
 TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS
 compatibility. Please use these products in this document in compliance with all applicable laws and regulations
 that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
 occurring as a result of noncompliance with applicable laws and regulations.